



E3.S, 7.5mm, NVMe™ SSD  
1.92TB, 3.84TB, 7.68TB<sup>1</sup>

## Highlights

- Experience exceptional PCIe Gen5 performance in multiple capacities up to 7.68TB<sup>1</sup>, perfect for compute-intensive applications
- Engineered for minimal power consumption, optimizing efficiency and reducing operational costs without compromising performance
- Achieve optimized solutions at low cost for your enterprise's mixed workloads with high-speed random read performance
- Delivering consistent QoS, even under heavy workloads, helping latency during mission-critical operations
- U.2 and E1.S options also available, ensuring scalability and flexibility to meet your enterprise storage needs
- Benefit from enterprise-class features including Power Loss Protection, End-to-End Data Path Protection, and TCG security and encryption, all backed by a 5-year limited warranty<sup>2</sup>

## Applications/Environments

- AI Model Training and Inference, Machine Learning, Deep Learning
- Hyperscale Cloud and Enterprise Datacenters
- Compute Intensive Applications
- Standard Compute, High CPU, High GPU, HPC Workloads
- Big Data, Data Analytics, Data Modeling, Predictive Analysis

## Redefining the limits for high-performance storage

Be ready for the future of mission critical workloads with the SanDisk® DC SN861. The latest SanDisk SSD with a cutting-edge PCIe® Gen5 enterprise-class speeds, the DC SN861 offers exceptional performance and multiple capacities up to 7.68TB<sup>1</sup>. With high random read speeds and low power consumption, the DC SN861 is optimized for compute-intensive AI and machine learning applications, ensuring superior read/write performance, extremely low latency, and maximize IOPs/Watt. The DC SN861 also provides a rich feature set including NVMe™ 2.0 and OCP 2.0 support, 1 DWPD, and a 5-year limited warranty<sup>2</sup>, making it the ideal solution for hyperscale, cloud, and enterprise data centers.

## Features

### Ready for the Demands of AI Workloads

Designed to handle compute-intensive AI and machine learning applications which require high bandwidth and low latency.

### Superior Performance and Capacity

Experience future-ready PCIe Gen5 read/write speeds with multiple capacities up to 7.68TB<sup>1</sup>.

### Designed for Power Efficiency

Architected to provide heightened performance per watt, optimizing power efficiency and reducing operational costs.

### Outstanding Mixed Workload Performance

High-speed random reads provide enhanced solutions at low cost for your enterprise.

### Optimized for Quality of Service (QoS)

Reduce latency during mission-critical workloads, delivering consistent Quality of Service (QoS) for your applications, even under heavy workloads.

### Rich Enterprise Features

Benefit from enterprise-class features such as Power Loss Protection, End-to-End Data Path Protection, and TCG security and encryption, helping ensure data integrity and security.

### Future-Ready Data Infrastructure

Designed to support NVMe 2.0, and NVMe MI 1.2c, and OCP 2.0 supportive, for enhanced scalability and efficiency.

# SanDisk DC SN861

## DATA SHEET

## DATA CENTER SOLID STATE DRIVE

### Product Information

|                        |        |               |        |
|------------------------|--------|---------------|--------|
| Capacity <sup>1</sup>  | 1.92TB | 3.84TB        | 7.68TB |
| Endurance <sup>3</sup> |        | 1 DWPD        |        |
| Security               |        | TCG OPAL 2.01 |        |
| Form Factor            |        | E3.S          |        |
| Interface              |        | PCIe Gen5×4   |        |
| NVMe Specification     |        | NVMe v2.0     |        |

### Performance

|  |        |        |        |
|--|--------|--------|--------|
| Read Throughput (max MB/S, Seq 128KiB) <sup>4</sup>  | 13,700 | 13,700 | 13,800 |
| Write Throughput (max MB/S, Seq 128KiB) <sup>4</sup> | 3,600  | 7,200  | 7,500  |
| Read IOPS (max, Rnd 4KiB) <sup>4</sup>               | 2,100K | 3,300K | 3,300K |
| Write IOPS (max, Rnd 4KiB) <sup>4</sup>              | 185K   | 385K   | 480K   |
| Read Latency (μS) <sup>5</sup>                       | 65     | 65     | 65     |
| Write Latency (μS) <sup>5</sup>                      | 8      | 8      | 8      |

### Reliability

|   |  |                       |  |
|---|--|-----------------------|--|
| MTTF <sup>6</sup> (hours, projected)                  |  | 2.5M                  |  |
| Uncorrectable Bit Error Rate (UBER)                   |  | 1 in 10 <sup>17</sup> |  |
| Annualized Failure Rate <sup>6</sup> (AFR, projected) |  | 0.35%                 |  |
| Limited Warranty <sup>2</sup>                         |  | 5 years               |  |

### Power Management

|                           |  |                                   |  |
|---------------------------|--|-----------------------------------|--|
| Requirement (DC, +/- 10%) |  | +12v                              |  |
| Operating Mode            |  | 12W, 14W, 16W, 18W, 20W (Default) |  |
| Idle (Average)            |  | -5W                               |  |

### Physical Size

|                             |  |                 |  |
|-----------------------------|--|-----------------|--|
| z-height (mm)               |  | 7.5mm           |  |
| Dimensions (width x Length) |  | 76mm x 112.75mm |  |
| Weight (g, max)             |  | 117g            |  |

### Environmental

|  |  |               |  |
|--|--|---------------|--|
| Operating Temperature (Ambient) <sup>7</sup> |  | 0°C to 70°C   |  |
| Non-Operating temperature <sup>8</sup>       |  | -40°C to 85°C |  |

### Ordering Information

| Capacity <sup>1</sup> | 1.92TB         | 3.84TB         | 7.68TB         |
|-----------------------|----------------|----------------|----------------|
| OTS Number            | OTS2584        | OTS2585        | OTS2586        |
| Model Number          | SDS6BA119PBPA7 | SDS6BA138PBPA7 | SDS6BA176PBPA7 |

<sup>1</sup> One terabyte (TB) is equal to 1,000GB (one trillion bytes). Actual user capacity may be less due to operating environment.

<sup>2</sup> The warranty for the product will expire on the earlier of (i) the date when the flash media has reached one-percent (1%) of its remaining life or (ii) the expiration of 5 years.

<sup>3</sup> NAND Endurance.

<sup>4</sup> Based on internal testing. Performance will vary by capacity point, or with the changes in useable capacity. Consult product manual for further details. All performance measurements are in full sustained mode and are peak values. IOPS = input/output operations persecond. Subject to change.

<sup>5</sup> Average random latency at 4KiB, QD=1.

<sup>6</sup> MTTF and AFR specifications will be based on a sample population and are estimated by statistical measurements and acceleration algorithms under typical operating conditions for this drive model. MTTF and AFR ratings do not predict an individual drive's reliability and do not constitute a warranty.

<sup>7</sup> Composite temperature reading

<sup>8</sup> Values are based on ambient temperature. Avoid non-operational exposure to temperatures in excess of 40°C for periods exceeding three months.



951 Sandisk Drive  
Milpitas, CA 95035, USA  
www.sandisk.com

SanDisk, the SanDisk logo, are registered trademarks or trademarks of SanDisk Corporation or its affiliates in the US and/or other countries. The NVMe word mark is a trademark of NVM Express, Inc. PCIe is a registered trademark of PCI-SIG. All other marks are the property of their respective owners. ©2024 SanDisk Corporation or its affiliates. All rights reserved.

Product specifications subject to change without notice. Pictures shown may vary from actual products. References to Western Digital products do not imply they will be made available in all regions.